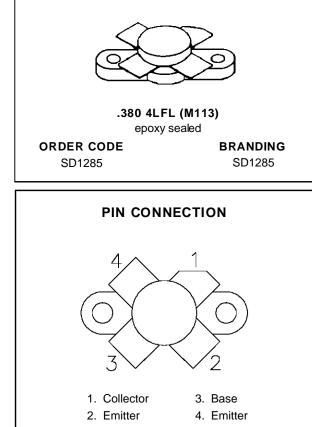


SD1285

RF & MICROWAVE TRANSISTORS HF SSB APPLICATIONS

- 30 MHz
- 12.5 VOLTS
- COMMON EMITTER
- GOLD METALLIZATION
- ∎ IMD 30 dB
- POUT = 20 W MIN. WITH 15 dB GAIN



DESCRIPTION

The SD1285 is a 12.5 V epitaxial NPN planar transistor designed primarily for SSB communications. This device utilizes emitter ballasting to achieve extreme ruggedness under severe operating conditions.

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit	
Vсво	Collector-Base Voltage	36		
V _{CEO}	Collector-Emitter Voltage	18	V	
V _{EBO}	Emitter-Base Voltage	4.0	V	
lc	Device Current	4.5	А	
PDISS	Power Dissipation	80	W	
TJ	Junction Temperature +200		°C	
T _{STG}	Storage Temperature	– 65 to +150	°C	

THERMAL DATA

R _{TH(j-c)} Junction-Case Thermal Resistance	2.2	°C/W
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SD1285

ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

STATIC

Symbol	Test Conditions	Value			Unit		
		Min.	Тур.	Max.	Onit		
ВVсво	I _C = 50mA	$I_E = 0mA$		36			V
BVCES	I _C = 50mA	$V_{BE} = 0V$		36	_		V
BV _{CEO}	$I_{C} = 50 \text{mA}$	$I_B = 0mA$		18	—	_	V
BV _{EBO}	I _E = 5mA	$I_C = 0mA$		4.0	_		V
ICES	$V_{CE} = 15V$	$I_E = 0mA$		_	_	5	mA
hFE	$V_{CE} = 5V$	Ic = 1A		10	_	200	_

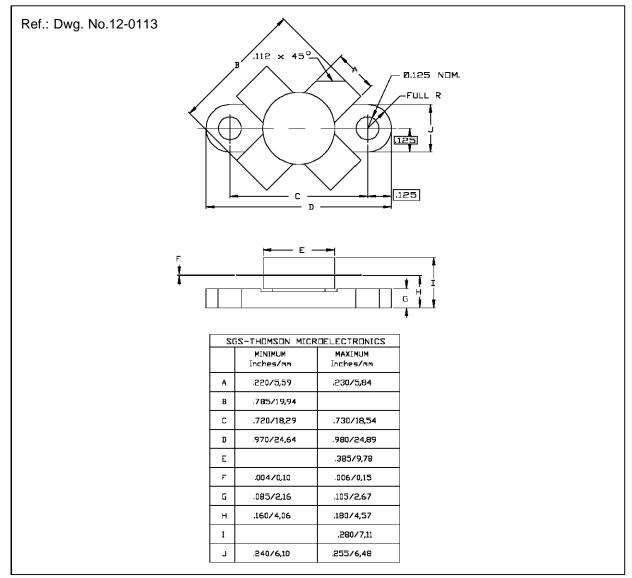
DYNAMIC

Symbol	Test Conditions			Value			Unit
Symbol				Min.	Тур.	Max.	Unit
Роит	f = 30 MHz	$V_{CC} = 12.5 V$	$I_{CQ} = 25 \text{ mA}$	20	_		W
GP	f = 30 MHz	$V_{CC} = 12.5 V$	$I_{CQ} = 25 \text{ mA}$	15	18		dB
IMD	f = 30 MHz	$V_{CC} = 12.5 V$	$I_{CQ} = 25 \text{ mA}$	—	_	- 30	dB
C _{OB}	f = 1 MHz	$V_{CB} = 12.5 V$		_	100		pF

Note: $P_{IN} = 0.65 \text{ W}$



PACKAGE MECHANICAL DATA



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